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# Increasing SSD Performance and Lifetime with Multi-stream Technology

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## Agenda

- NAND flash characteristics
- Multi-stream
  - Multi-stream concept
  - Multi-stream system architecture
  - Multi-stream operation
- Performance benefit
- **Summary**
- 🗖 Q&A



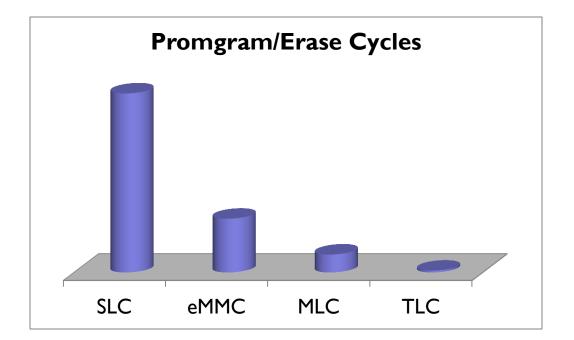
# **NAND Flash Characteristics**

- Operation
  - Read/Program/Erase
- Operation unit
  - Read/Program: Page
  - Erase: block (= multiple pages)
- Out-of-place update
  - In-place update(=overwrite) NOT allowed
    - Invalidate overwritten data
  - Page MUST be erased before programming(writes)
    - □ Program/Erase (P/E) cycles
    - Needs garbage collection operation

Efficient data placement increases performance with reduced garbage collection overhead

# NAND Flash Characteristics (Cont'd)

□ Limited number of Program/Erase cycles



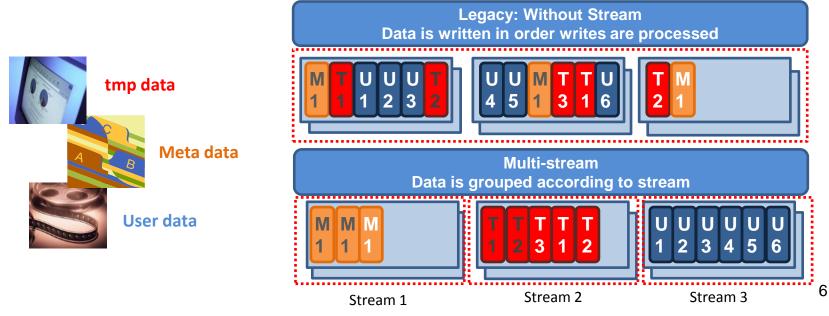
Efficient data placement increases lifetime of SSD(endurance)



## **Multi-stream**

**Provide better endurance, improved performance, and consistent latency** 

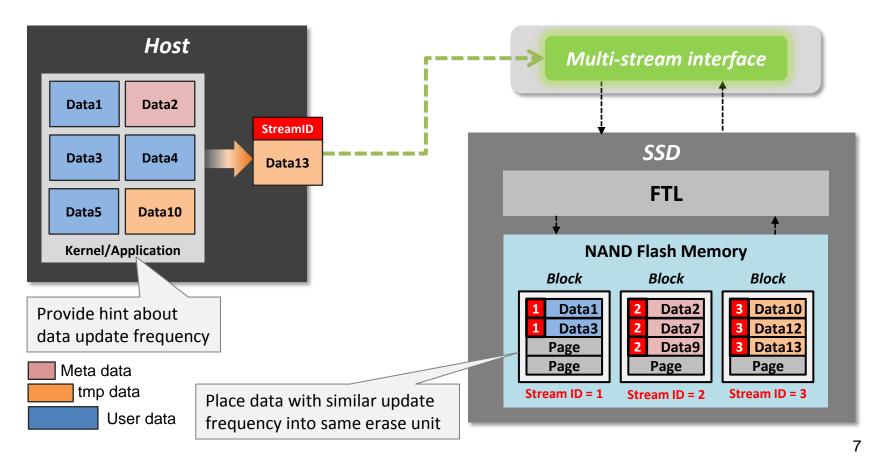
- Allow host to associate each write operation with a stream
- All data associated with a stream is expected to be invalidated at the same time (e.g., updated, trimmed, unmapped, deallocated)
- Align NAND block allocation based on application data characteristics(e.g., lifetime)





# **Multi-stream Operation**

Mapping data with different lifetime to different streams

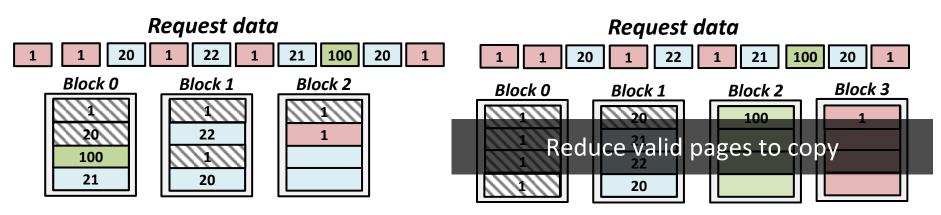




# **Operation Example**

Efficient data placement with multi-stream

Reduce GC overheads -> better performance and lifetime!



Legacy: Without Stream

Multi-Stream

For effective multi-streaming, proper mapping of data to streams is important!



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# **FIO Performance Measurement System**

#### Hardware

- Quad Core Intel i7-4790 CPU 3.60GHz
- 16GB memory

### Software

- Ubuntu 14.04 LTS, v4.0.3 Kernel with multi-stream patch
- **FIO 2.2.5** with multi-stream patch

## Device

Multi-stream enabled NVMe SSD



# **Performance Measurement Configuration**

□ Four sequential writes jobs 1+ random read job

Different data lifetime: 1x, 10x, 33x, 55x

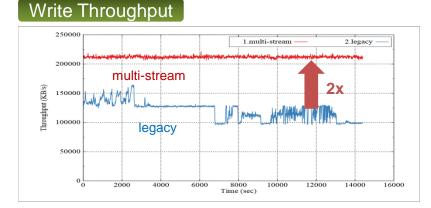
Precondition

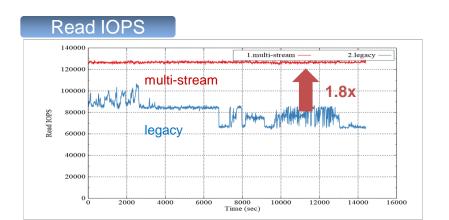
2 hours with four-write jobs

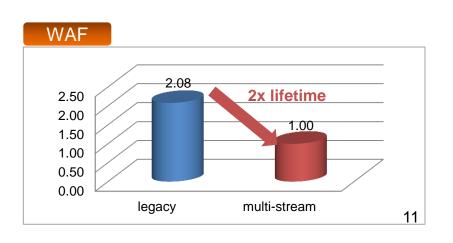


# Four Streams – Read/Write(70%/30%)

- Reads
  - Jobs: 6
  - Block size: 4k
  - Iodepth: 64
- Writes
  - Jobs: 4
  - Block size: 128k
  - Iodepth: 1









## **Standards**

#### □ SCSI/SAS: Completed in May, 2015

□ Standard spec:

http://www.t10.org/cgi-bin/ac.pl?t=f&f=sbc4r10.pdf

NVMe: standardization ongoing
SATA: standardization ongoing



## **Summary**

- With multi-stream, SSDs can be more efficiently used for
  - Consistent better performance
  - Better endurance (=better SSD lifetime)
- With multi-stream
  - FIO: more than 2x SSD lifetime in addition to the decent I/O performance enhancement









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